

SSM3K126TU

High-Speed Switching Applications

- 4.0 V drive
- Low ON-resistance: $R_{on} = 43 \text{ m}\Omega$ (max) (@ $V_{GS} = 4.0 \text{ V}$)
- $R_{on} = 32 \text{ m}\Omega$ (max) (@ $V_{GS} = 10 \text{ V}$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	30	V
Gate-Source voltage		V _{GSS}	± 20	V
Drain current	DC	I _D	3.9	A
	Pulse	I _{DP}	7.8	
Drain power dissipation		P _D (Note 1)	800	mW
		P _D (Note 2)	500	
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a ceramic board.
(25.4 mm × 25.4 mm × 0.8 t, Cu Pad: 645 mm²)

Note 2: Mounted on a FR4 board.
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm²)

Unit: mm

Technical drawing of a MOSFET structure with dimensions:

- Width: 2.1 ± 0.1 mm
- Length: 1.7 ± 0.1 mm
- Thickness: $0.3^{+0.1}_{-0.05}$ mm
- Side wall thickness: 0.166 ± 0.05 mm
- Source/Drain width: 0.7 ± 0.05 mm
- Source/Drain thickness: 0.65 ± 0.05 mm
- Gate thickness: 2.0 ± 0.1 mm
- Gate width: 1.7 ± 0.1 mm

Labels:

- 1: Gate
- 2: Source
- 3: Drain

UFM

Weight: 6.6 mg (typ.)

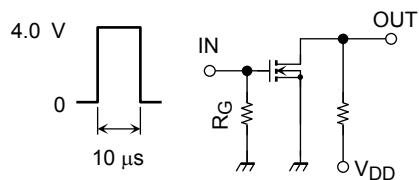
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Drain-Source breakdown voltage	$V_{(BR) DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	30	—	—	V	
	$V_{(BR) DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -20 \text{ V}$	15	—	—		
Drain cutoff current	I_{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	μA	
Gate leakage current	I_{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	± 1		
Gate threshold voltage	V_{th}	$V_{DS} = 5 \text{ V}, I_D = 1 \text{ mA}$	1.0	—	2.6	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 5 \text{ V}, I_D = 3.0 \text{ A}$ (Note 3)	13.5	27	—	S	
Drain-Source ON-resistance	$R_{DS(ON)}$	$I_D = 3.0 \text{ A}, V_{GS} = 10 \text{ V}$ (Note 3)	—	20	32	$\text{m}\Omega$	
		$I_D = 3.0 \text{ A}, V_{GS} = 4.0 \text{ V}$ (Note 3)	—	28	43		
Input capacitance	C_{iss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	720	—	pF	
Output capacitance	C_{oss}		—	128	—		
Reverse transfer capacitance	C_{rss}		—	115	—		
Total Gate Charge	Q_g	$V_{DS} = 15 \text{ V}, I_{DS} = 3.9 \text{ A}$ $V_{GS} = 10 \text{ V}$	—	20.5	—	nC	
Gate-Source Charge	Q_{gs}		—	16.2	—		
Gate-Drain Charge	Q_{gd}		—	4.3	—		
Switching time	Turn-on time	t_{on}	$V_{DD} = 15 \text{ V}, I_D = 1.0 \text{ A},$ $V_{GS} = 0 \sim 4.0 \text{ V}, R_G = 10 \Omega$	—	20	—	ns
	Turn-off time	t_{off}		—	24	—	
Drain-Source forward voltage	V_{DSF}	$I_D = -3.9 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 3)	—	-0.8	-1.2	V	

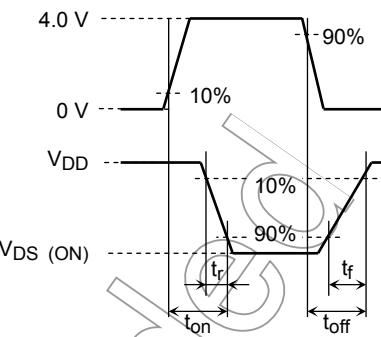
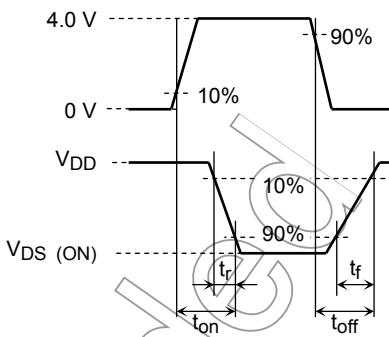
Note 3: Pulse test

Switching Time Test Circuit

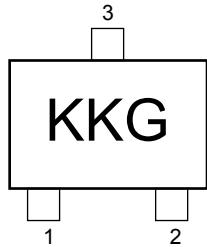
(a) Test Circuit



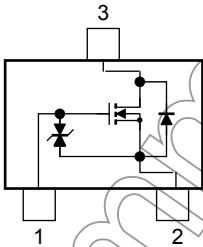
$V_{DD} = 15 \text{ V}$
 $R_G = 10 \Omega$
 $D.U. \leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN} (c) V_{OUT} 

Marking



Equivalent Circuit (top view)



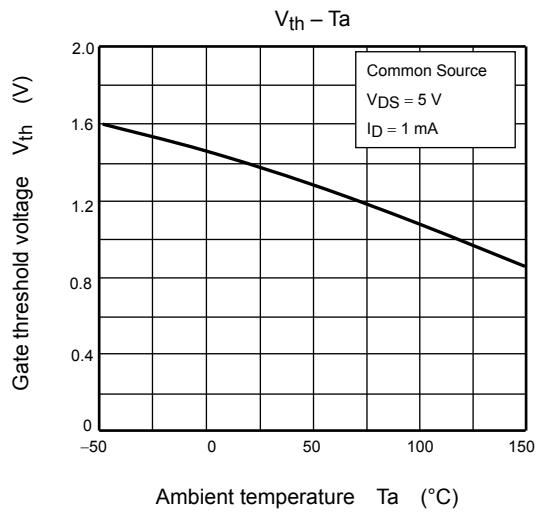
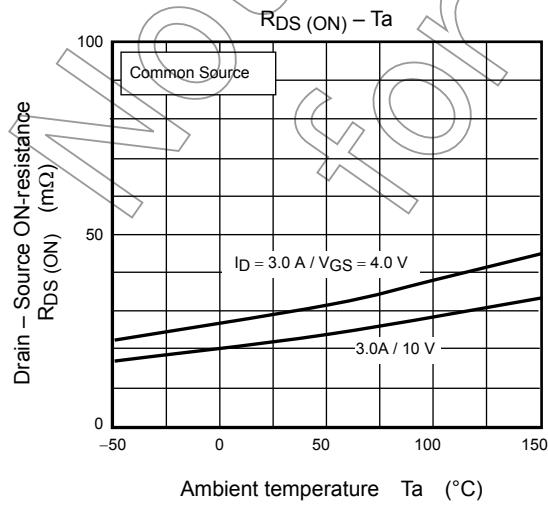
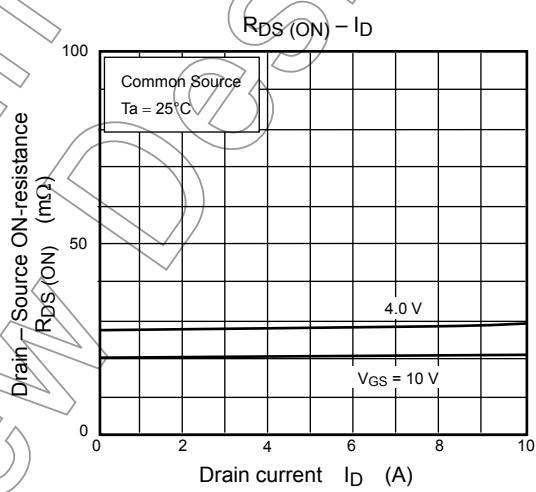
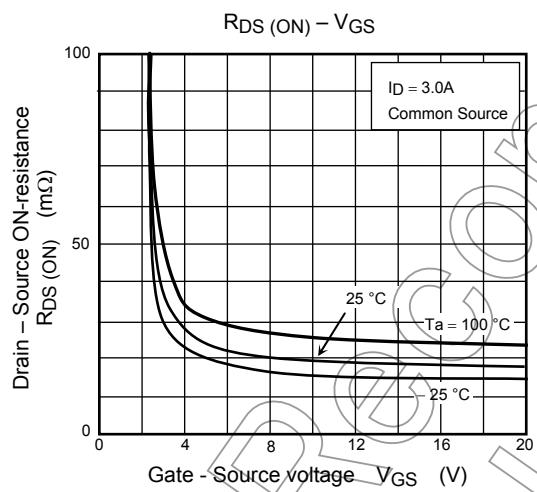
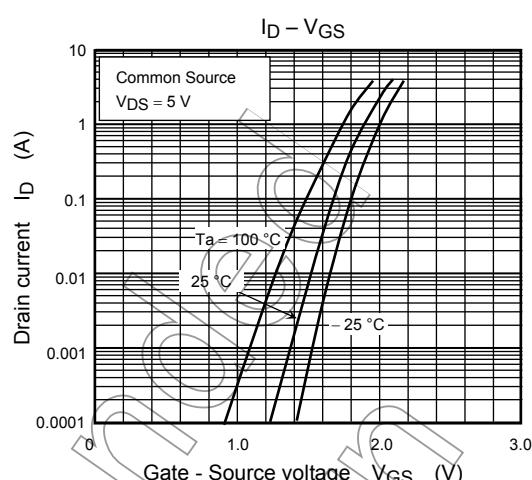
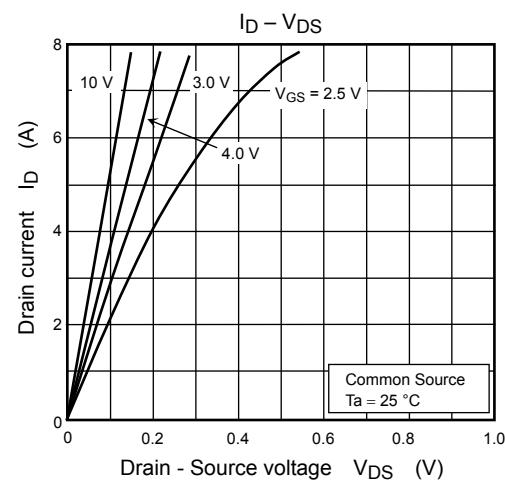
Notice on Usage

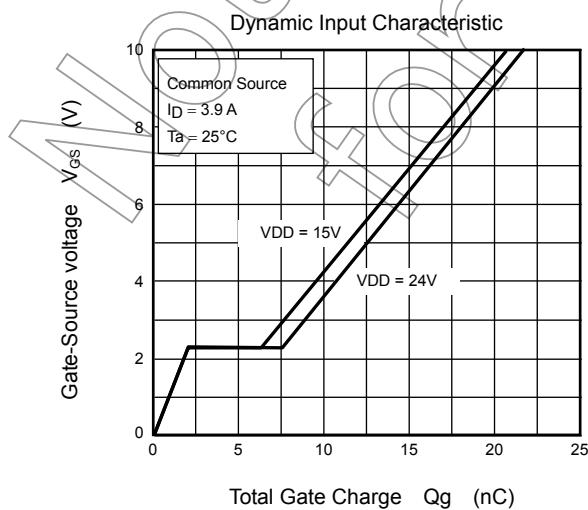
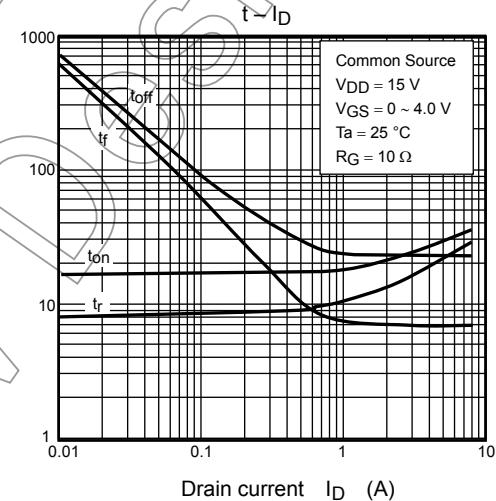
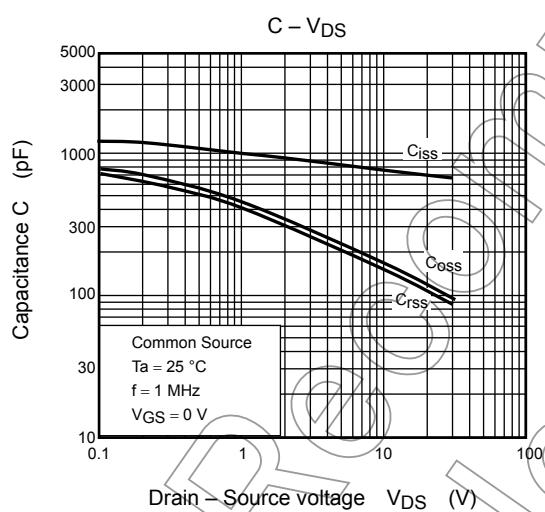
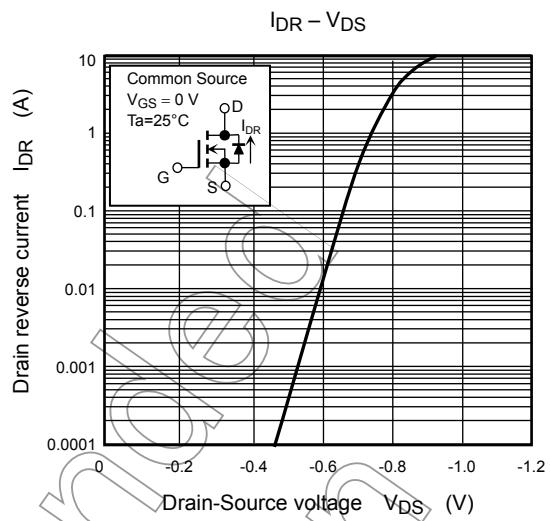
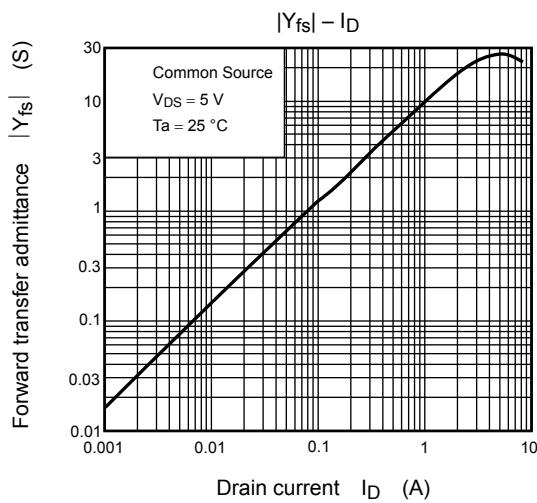
V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = 1 \text{ mA}$ for this product. For normal switching operation, $V_{GS}(\text{on})$ requires a higher voltage than V_{th} , and $V_{GS}(\text{off})$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS}(\text{off}) < V_{th} < V_{GS}(\text{on})$.)

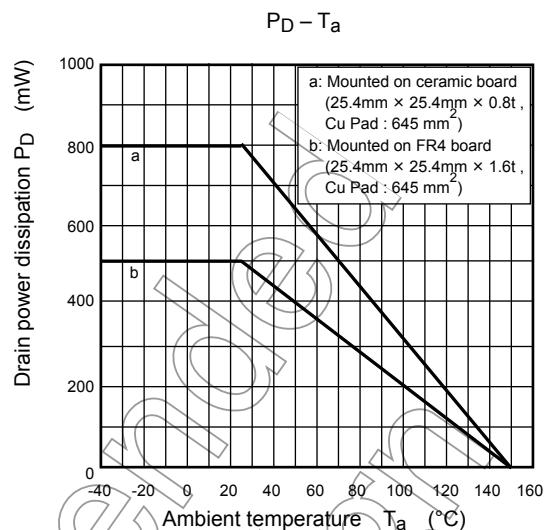
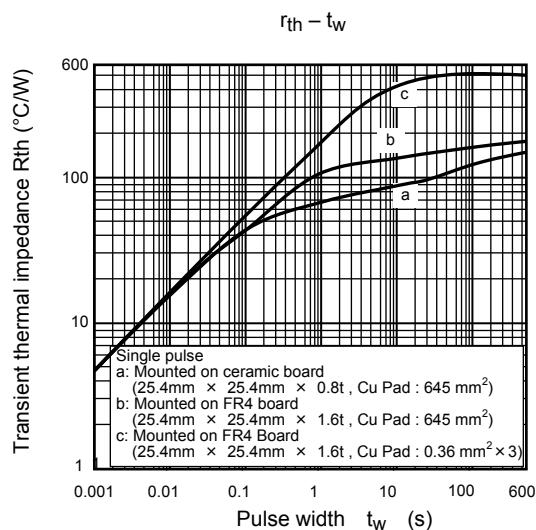
Take this into consideration when using the device.

Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.







Not Recommended for New Designs

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